

SGM8437-2 Current Feedback, Wide-Band High-Current Output Amplifier

GENERAL DESCRIPTION

The SGM8437-2 is a current feedback, wide-band high-current output amplifier with high voltage, low noise and high slew rate performance. These features make SGM8437-2 very suitable for wide-band heavy load applications.

The SGM8437-2 can operate from 8V to 30V single supply or from \pm 4V to \pm 15V dual supplies. And it maintains wide bandwidth and high linearity over the whole full-scale range of power supply.

A disable control (DIS) pin is used to control the operation modes of the device. When DIS pin is high or floating, SGM8437-2 is in power-down mode. When DIS pin is low, SGM8437-2 is in full-power working mode.

The SGM8437-2 is available in a Green TQFN-4×5-24AL package. It operates over an ambient temperature range of -40 $^{\circ}$ C to +85 $^{\circ}$ C.

FEATURES

- Current Feedback Amplifier
- Support Single or Dual Power Supplies: 8V to 30V or ±4V to ±15V
- Supply Current: 18mA (TYP)
- Power-Down Current: 35µA (TYP)
- Low Input Voltage Noise Density: 10nV/√Hz
- High Slew Rate for Differential Signal: 800V/µs
- Amplifier A and B are Stable at Gain ≥ 2
- Output Over-Voltage Protection and Voltage Clamping Protection
- Over-Temperature Protection
- Disable Control Pins for Low-Power Design
- -40°C to +85°C Operating Temperature Range
- Available in a Green TQFN-4×5-24AL Package

APPLICATIONS

Test Equipment Amplifiers Cable Drivers

TYPICAL APPLICATION

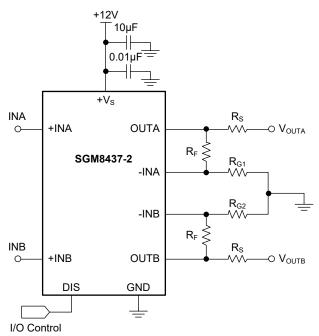


Figure 1. Typical Application Circuit

SGM8437-2

Current Feedback, Wide-Band High-Current Output Amplifier

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8437-2	TQFN-4×5-24AL	-40°C to +85°C	SGM8437-2YTQY24G/TR	SGM84372 YTQY24 XXXXX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

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				٦

Vendor Code
Trace Code
Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, +V _S to -V _S	-0.3V to 32V
+V _S Voltage to GND	-0.3V to 30V
-Vs Voltage to GND	-30V to 0.3V
DIS Voltage to GND	-0.3V to 5.5V
Package Thermal Resistance	
TQFN-4×5-24AL, θ _{JA}	
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	4000V
CDM	

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range-40°C to +85°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

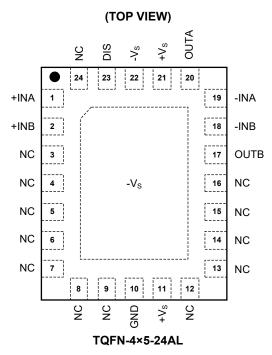
DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.



SGM8437-2

PIN CONFIGURATION



PIN DESCRIPTION

PIN	NAME	FUNCTION
1	+INA	Non-Inverting Input of Amplifier A.
2	+INB	Non-Inverting Input of Amplifier B.
3-9, 12-16, 24	NC	No Internal Connection.
10	GND	Ground. The GND pin must be connected with external ground.
11, 21	+Vs	Positive Power Supply for Amplifiers. (8V to 30V for single power supply and +4V to +15V for dual power supplies.)
17	OUTB	Output of Amplifier B.
18	-INB	Inverting Input of Amplifier B.
19	-INA	Inverting Input of Amplifier A.
20	OUTA	Output of Amplifier A.
22	-Vs	Negative Power Supply Voltage. For single power supply application, -V _S pin must be connected to external ground. For dual power supplies application, -V _S pin must be connected to external -4V to -15V negative power supply.
23	DIS	Disable Control Pin. The SGM8437-2 is in power-down (disabled) mode if the DIS pin is floating.
Exposed Pad	-Vs	Must be connected to $-V_S$ for optimal thermal performance. Connecting to other pins is not allowed.



ELECTRICAL CHARACTERISTICS

 $(V_S = 8V \text{ to } 30V, V_{CM} = 1/2V_S, R_F = 1.2k\Omega, R_L = 50\Omega \text{ and } A_V = 10, Full = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ typical values are at } T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Supply Characteristics							
Operating Voltage Range	Vs		Full	8		30	V
			+25°C		18	21	mA
Positive Supply Current	+I _S (Full-Power)	All outputs at 0V	Full			24	
No metione Descente Operation			+25°C	-21	-18		
Negative Supply Current	-I _S (Full-Power)	All outputs at 0V	Full	-24			mA
		All outputs at 0V, V_{DIS} = 3.3V, V_{S} =	+25°C		35	50	
Positive Supply Current	+I _S (Power-Down)	28V	Full			130	μA
Negative Supply Current		All outputs at 0V, V _{DIS} = 3.3V, V _S =	+25°C	-40	-30		
Negative Supply Current	-I _S (Power-Down)	28V	Full	-120			μA
	PSRR+	1/(-9)/(+0.20)/(-0.00)	+25°C	90	100		
Power Supply Principal	T ORACI	$V_{\rm S} = 8V$ to 30V	Full	82			dD
Power Supply Rejection Ratio	DEDD	(9)(+-20)(+25°C	84	94		dB
	PSRR-	$V_{\rm S} = 8V$ to 30V	Full	78			
Input Characteristics	•						
	N/		+25°C		6	12	m) /
Input Offset Voltage	V _{os}		Full			18	mV
Input Offset Voltage Drift	$\Delta V_{OS} / \Delta T$		Full		0.1		mV/°C
Inverting Input Dies Current	-I _B		+25°C		18	35	μA
Inverting Input Bias Current			Full			45	
Inverting Input Bias Current Drift	ΔΙ _{Β-} /ΔΤ		Full		0.1		µA /℃
Non-Inverting Input Pige Current			+25°C		15	45	5
Non-Inverting Input Bias Current	+I _B		Full			320	nA
Non-Inverting Input Bias Current Drift	ΔI _{B+} /ΔT		Full		0.3		nA/°C
Input Common Mode Voltage Range	V _{CM}		Full	(-V _S) + 4		(+V _S) - 4	V
		y' = 10y' y' = 4y' to 9y'	+25°C	74	82		
Common Mode Poinction Potio	CMRR	$V_{\rm S}$ = 12V, $V_{\rm CM}$ = 4V to 8V	Full	64			dB
Common Mode Rejection Ratio	CIVIRR	$V_{\rm S} = 30V, V_{\rm CM} = 4V$ to 26V	+25°C	82	90		uБ
		$v_{\rm S} = 30v, v_{\rm CM} = 4v \ 10 \ 20v$	Full	74			
Transimpedance ⁽¹⁾	R _{OL}		Full		18		MΩ
Input High Voltage	V _{IH}	DIS input	Full	2			V
Input Low Voltage	VIL	DIS input	Full			0.8	V
Input Pin Current	I _{IH}	DIS input, V _{DIS} = 3.3V	Full		-0.2	3	μA
	I _{IL}	DIS input, V _{DIS} = 0V	Full	-3	-2		μΛ
Output Characteristics							
		$V_{\rm S}$ = 30V, $R_{\rm L}$ = 50 Ω	+25°C		2.5	3	
Output Voltage Swing from Rail	V _{OUT}	$V_{\rm S}$ = 30V, $R_{\rm L}$ = 100 Ω	+25°C		2.25		V
		$V_{\rm S}$ = 30V, $R_{\rm L}$ = open	+25°C		2		
Output Current	Ι _{ουτ}	$V_{\rm S} = 30 V, R_{\rm L} = 20 \Omega$	+25°C		±0.5		А

NOTE: 1. Specified by design.



Current Feedback, Wide-Band High-Current Output Amplifier

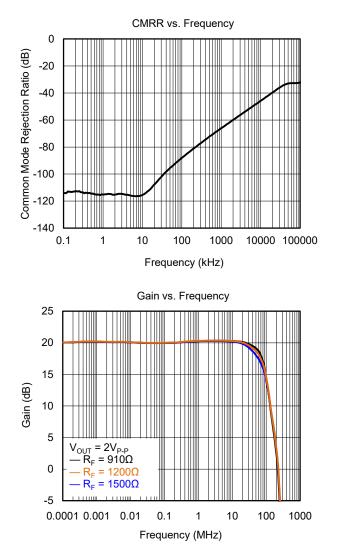
ELECTRICAL CHARACTERISTICS (continued) (V_S = 8V to 30V, V_{CM} = $1/2V_S$, R_F = $1.2k\Omega$, R_L = 50Ω and A_V = 10, Full = -40° C to $+85^{\circ}$ C, typical values are at T_A = $+25^{\circ}$ C, unless

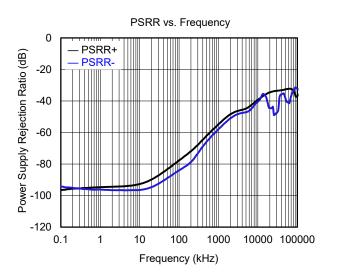
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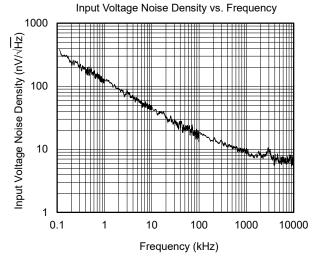
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS	
Dynamic Performance		-						
-3dB Small-Signal Bandwidth	BW	$V_{\rm S}$ = 30V, $V_{\rm OUT}$ = 2 $V_{\rm P-P}$	+25°C		75		MHz	
-3dB Large-Signal Bandwidth	BW	V _S = 30V, V _{OUT} = 10V _{P-P}	+25°C		35		MHz	
		V_{S} = 30V, f_{C} = 1MHz, V_{OUT} = 10 $V_{\text{P-P}}$	+25°C		-59			
2nd Harmonic Distortion	HD2	V_{S} = 30V, f _C = 2MHz, V_{OUT} = 10 $V_{\text{P-P}}$	+25°C		-60		dBc	
	ΠDZ	V_{S} = 30V, f _C = 3MHz, V_{OUT} = 10 $V_{\text{P-P}}$	+25°C		-54		UDC	
		$V_{S} = 30V, f_{C} = 10MHz, V_{OUT} = 10V_{P-P}$	+25°C		-35			
	HD3	V_{S} = 30V, f_{C} = 1MHz, V_{OUT} = 10 $V_{\text{P-P}}$	+25°C		-69		- dBc	
3rd Harmonic Distortion		V_{S} = 30V, f_{C} = 2MHz, V_{OUT} = 10 $V_{\text{P-P}}$	+25°C		-64			
Sid Harmonic Distortion		V_{S} = 30V, f_{C} = 3MHz, V_{OUT} = 10 $V_{\text{P-P}}$	+25°C		-60		uвс	
		$V_{S} = 30V, f_{C} = 10MHz, V_{OUT} = 10V_{P-P}$	+25°C		-57			
Slew Rate (Differential Signal)	SR	$V_{\rm S}$ = 30V, $V_{\rm OUT}$ = 20 $V_{\rm P-P}$	+25°C		800		V/µs	
Turn-On/Off Time	t _{EN}	From disable to enable time	+25°C		10		μs	
Turn-On/On Time	t _{DIS}	From enable to disable time	+25°C		160		ns	
Noise							_	
Input Voltage Noise Density	en	f = 1MHz	+25°C		10		nV/\sqrt{Hz}	
Over-Temperature Protection			•		•	•		
Over-Temperature Protection					150		°C	
Over-Temperature Protection Hysteresis					5		°C	

TYPICAL PERFORMANCE CHARACTERISTICS

At T_A = +25°C, V_S = ±15V, unless otherwise noted.

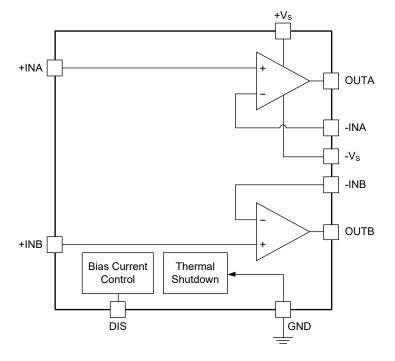






SGM8437-2

FUNCTIONAL BLOCK DIAGRAM







APPLICATION INFORMATION

Figure 1 shows a typical application circuit for SGM8437-2.

Power Control Function

The SGM8437-2 supports power control operation. Its supply current is controlled by the digital inputs DIS. DIS pin is pulled high internally. The device immediately enters power-down mode when DIS pin is floating.

The truth table of the SGM8437-2 is shown in Table 1.

Table 1. Working Modes of SGM8437-2

DIS Pin	Operation
0	Full-Power Working Mode.
1	Power-Down Mode.
Floating	Power-Down Mode.

Breakdown Supply Voltage

If the amplifier is being used in an application that is part of a regulated power grid, the ability to withstand a supply voltage that is higher than the recommended voltage is important to ensure robustness.

In order to estimate the margin beyond the maximum supply voltage, several randomly selected samples are tested to show the robustness of SGM8437-2.

Figure 3 shows the configuration of this test. The SGM8437-2 is tested by manually increasing the supply voltage in 1V steps while simultaneously recording the supply current. This operation is performed from 28V until internal device is breakdown. Five samples are subjected to this test, and the results are shown in Figure 4.

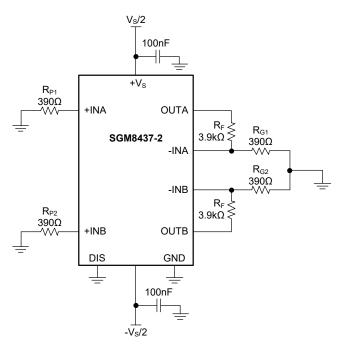


Figure 3. Breakdown Supply Voltage Test Configuration

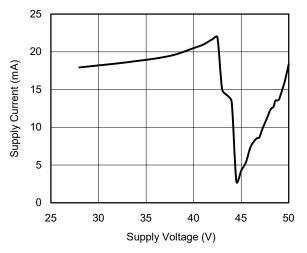


Figure 4. Supply Current vs. Supply Voltage

Page

REVISION HISTORY

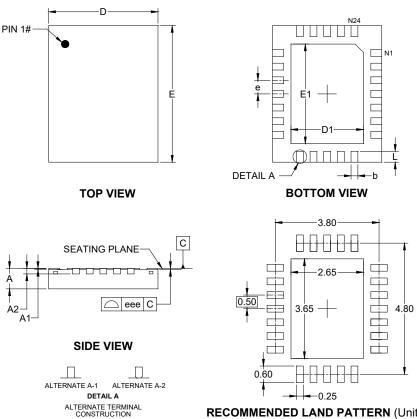
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (JUNE 2024) to REV.A

Changed from product preview to production data	All



PACKAGE OUTLINE DIMENSIONS TQFN-4×5-24AL



RECOMMENDED LAND PATTERN (Unit: mm)

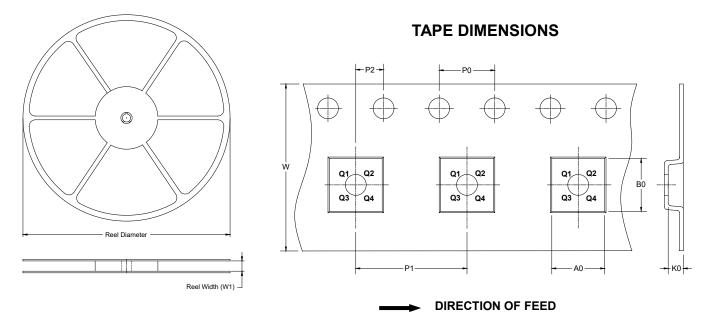
Sympol	Dir	Dimensions In Millimeters						
Symbol	MIN	NOM	МАХ					
A	0.700	-	0.800					
A1	0.000	-	0.050					
A2		0.203 REF						
b	0.200 -		0.300					
D	3.900	-	4.100					
E	4.900 -		5.100					
D1	2.550	2.550 -						
E1	3.550	-	3.750					
е	0.500 BSC							
L	0.300	-	0.500					
eee		0.080						

NOTE: This drawing is subject to change without notice.



TAPE AND REEL INFORMATION

REEL DIMENSIONS



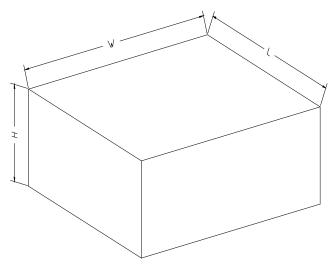
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TQFN-4×5-24AL	13″	12.4	4.30	5.30	1.10	4.0	8.0	2.0	12.0	Q1



CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length Width (mm) (mm)		Height (mm)	Pizza/Carton	
13″	386	280	370	5	DD0002

